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## \*BIBDATASHEET\*

Bib Data Sheet

**CONFIRMATION NO. 4915** 

SERIAL NUMBER 10/762,361	FILING DATE 01/23/2004 RULE	CLASS 438	GROUP ART UNIT 2812		D	ATTORNEY OCKET NO. OKI.206D3
APPLICANTS						
Masahiro Yoshida, Tokyo, JAPAN;						
Shunichi Tokitoh, Tokyo, JAPAN;						
This application is a DIV of 10/320,660 12/17/2002 PAT 6,700,167 which is a DIV of 09/759,639 01/16/2001 PAT 6,528,854  FOREIGN APPLICATIONS  JAPAN 2000-010250 01/17/2000  IF REQUIRED, FOREIGN FILING LICENSE GRANTED						
** 04/26/2004 Foreign Priority claimed	Ø <sub>yes</sub> □ no	OTATE OR	CUE	TC T(	TAL	INDEPENDENT
35 USC 119 (a-d) conditions			SHEE			
Verified and Acknowledged Ex		itials COUNTRY	DRAW 23		AIMS 20	CLAIMS 3
ADDRESS 20987 VOLENTINE FRANCOS, & WHITT PLLC ONE FREEDOM SQUARE 11951 FREEDOM DRIVE SUITE 1260 RESTON, VA 20190						
TITLE METHOD OF MANUFACTURING A SEMICONDUCTOR DEVICE INCLUDING A MOSFET WITH NITRIDE SIDEWALLS						
	☐ All Fees					
□ 1.16					Fees (Filing)	